Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: |
|---|
| Glass |
| |
| Overall Length: 0.180 inches |
| |
| Terminal Length: |
| |
| Overall Diameter: |
| 0.075 inches |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation: |
| Do-35 |
| Electrode Internally-electrically Connected To Case: |
| Cathode |
| |
| |
| Features Provided: |
| Hermetically sealed case |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 75.0 reverse voltage, dc |
| Current Rating Per Characteristic: |
| 150.00 milliamperes source cutoff current horsepower metric |
| Power Rating Per Characteristic: |
| 500.0 milliwatts small-signal input power, common-collector preset |
| Maximum Operating Tempurature Per Measurement Point: |
| 200.0 degrees celsius ambient air |
| Terminal Type And Quantity: |
| 2 uninsulated wire lead |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |
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